

Trench IGBT Modules

SEMiX303GB12E4p

Features*

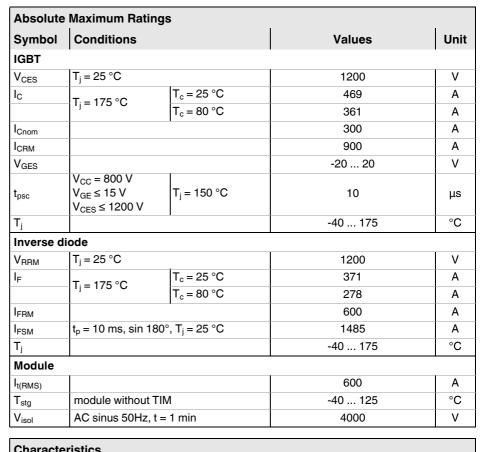
- · Homogeneous Si
- Trench = Trenchgate technology
- V_{CE(sat)} with positive temperature coefficient
- High short circuit capability
- · Press-fit pins as auxiliary contacts
- UL recognized, file no. E63532

Typical Applications

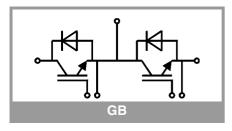
- · AC inverter drives
- UPS
- · Renewable energy systems

Remarks

- Product reliability results are valid for T_i=150°C
- V_{isol} between temperature sensor and power section is only 2500V
- For storage and case temperature with TIM see document "TP(*) SEMiX 3p"



Characteristics									
Symbol	Conditions		min.	typ.	max.	Unit			
IGBT									
V _{CE(sat)}	I _C = 300 A	T _j = 25 °C		1.80	2.05	V			
	V _{GE} = 15 V chiplevel	T _j = 150 °C		2.20	2.40	V			
V _{CE0}	chiplevel	T _j = 25 °C		0.80	0.90	V			
		T _j = 150 °C		0.70	0.80	V			
r _{CE}	V _{GE} = 15 V chiplevel	T _j = 25 °C		3.3	3.8	mΩ			
		T _j = 150 °C		5.0	5.3	mΩ			
$V_{\text{GE(th)}}$	$V_{GE} = V_{CE}, I_C = 11.4$	ł mA	5	5.8	6.5	V			
I _{CES}	$V_{GE} = 0 \text{ V}, V_{CE} = 12$			4.0	mA				
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		18.5		nF			
Coes		f = 1 MHz		1.22		nF			
C _{res}		f = 1 MHz		1.04		nF			
Q _G	V _{GE} = - 8 V+ 15 V			1695		nC			
R _{Gint}	T _j = 25 °C		2.5		Ω				
t _{d(on)}	$\begin{array}{l} \text{di/dt}_{\text{on}} = 5600 \text{ A/}\mu\text{s} \\ \text{di/dt}_{\text{off}} = 2400 \text{ A/}\mu\text{s} \end{array}$	T _j = 150 °C		180		ns			
t _r		T _j = 150 °C		55		ns			
E _{on}		T _j = 150 °C		23		mJ			
t _{d(off)}		T _j = 150 °C		470		ns			
t _f		T _j = 150 °C		110		ns			
E _{off}		T _j = 150 °C		38		mJ			
R _{th(j-c)}	per IGBT				0.094	K/W			
R _{th(c-s)}	per IGBT (λ _{grease} =0.	81 W/(m*K))		0.03		K/W			
R _{th(c-s)}	per IGBT, pre-appli material		0.021		K/W				





Trench IGBT Modules

SEMiX303GB12E4p

Features*

- · Homogeneous Si
- Trench = Trenchgate technology
- V_{CE(sat)} with positive temperature coefficient
- High short circuit capability
- Press-fit pins as auxiliary contacts
- UL recognized, file no. E63532

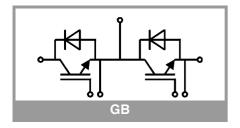
Typical Applications

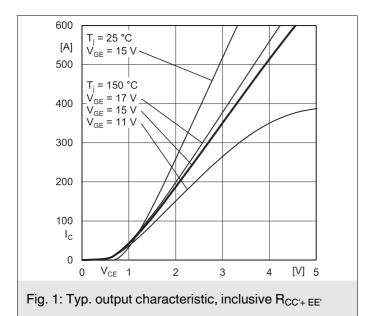
- · AC inverter drives
- UPS
- Renewable energy systems

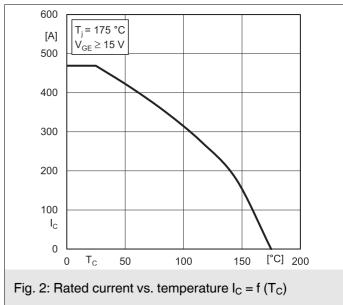
Remarks

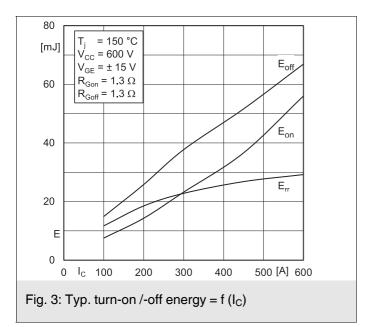
- Product reliability results are valid for T_j=150°C
- V_{isol} between temperature sensor and power section is only 2500V
- For storage and case temperature with TIM see document "TP(*) SEMiX 3p"

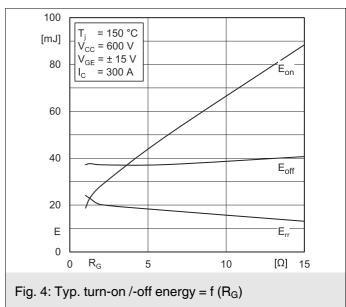
Characteristics										
Symbol	Conditions	min.	typ.	max.	Unit					
Inverse d	iode									
$V_F = V_{EC}$	I _F = 300 A	T _j = 25 °C		2.20	2.52	V				
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.16	2.47	V				
V _{F0}	chiplevel	T _j = 25 °C		1.30	1.50	V				
		T _j = 150 °C		0.90	1.10	V				
r _F	- chiplevel	T _j = 25 °C		3.0	3.4	mΩ				
		T _j = 150 °C		4.2	4.6	mΩ				
I _{RRM}	I _F = 300 A	T _j = 150 °C		330		Α				
Q_{rr}	di/dt _{off} = 6000 A/μs V _{GE} = -15 V	T _j = 150 °C		50		μC				
E _{rr}	$V_{GE} = -15 \text{ V}$ $V_{CC} = 600 \text{ V}$	T _j = 150 °C		23		mJ				
R _{th(j-c)}	per diode	-			0.155	K/W				
R _{th(c-s)}	per diode (λ _{grease} =0.81 W/(m*K))			0.046		K/W				
R _{th(c-s)}	per diode, pre-applied phase change material			0.037		K/W				
Module										
L _{CE}				20		nΗ				
R _{CC'+EE'}	measured per switch	T _C = 25 °C		1.2		mΩ				
		T _C = 125 °C		1.65		mΩ				
R _{th(c-s)1}	calculated without t		0.009		K/W					
R _{th(c-s)2}	including thermal confidence T_s underneath mod (m^*K)		0.014		K/W					
R _{th(c-s)2}	including thermal coupling, T _s underneath module, pre-applied phase change material			0.010		K/W				
Ms	to heat sink (M5)		3		6	Nm				
M_t		to terminals (M6)	3		6	Nm				
						Nm				
W					350	g				
Temperat	ture Sensor									
R ₁₀₀	T _c =100°C (R ₂₅ =5 kΩ)			493 ± 5%		Ω				
B _{100/125}	$R_{(T)} = R_{100} exp[B_{100/125}(1/T-1/T_{100})]; T[K];$			3550 ±2%		К				

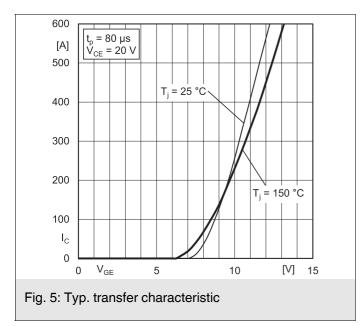


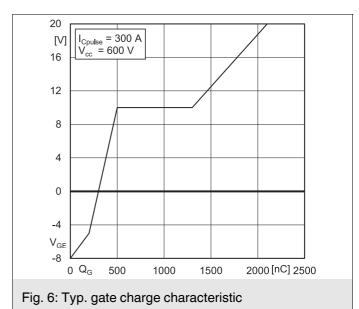


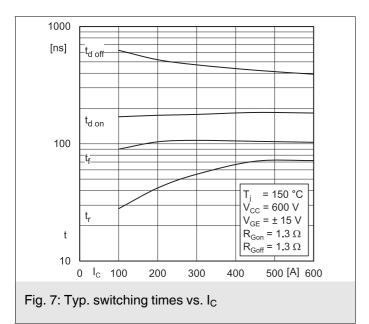


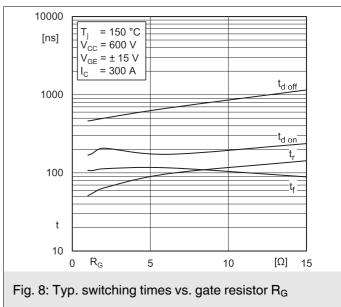


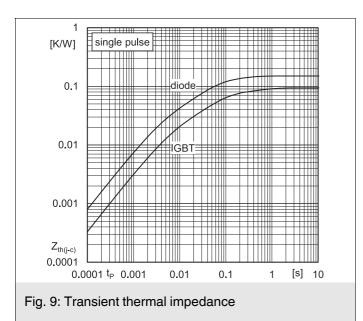


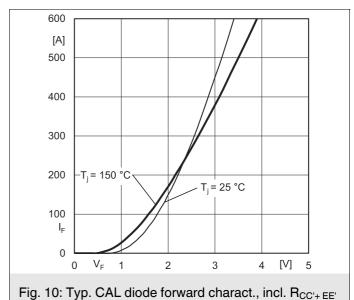


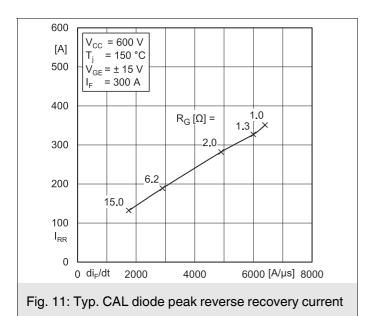


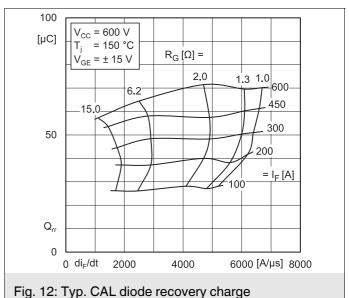


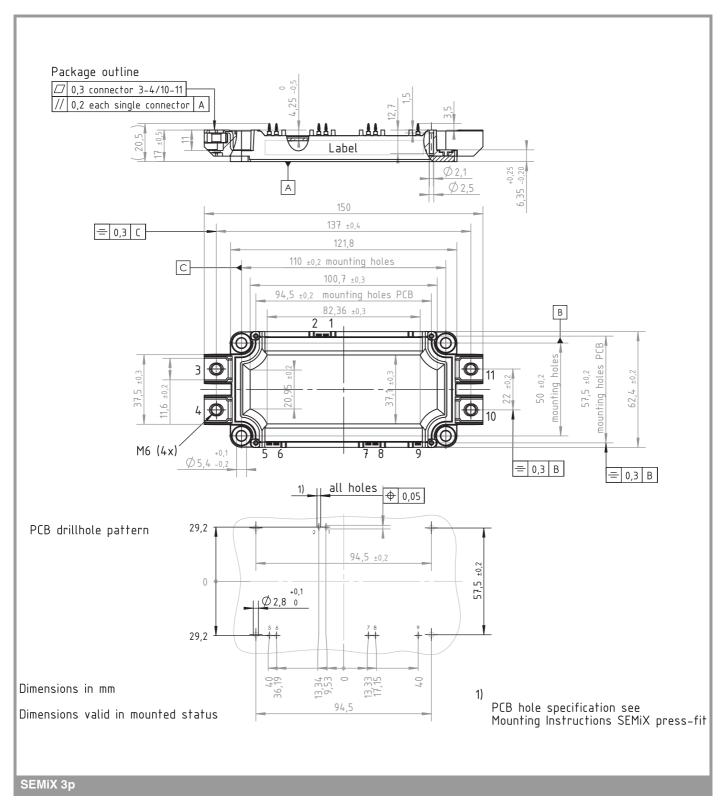












99 10/11 2 3

This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

*IMPORTANT INFORMATION AND WARNINGS

The specifications of SEMIKRON products may not be considered as guarantee or assurance of product characteristics ("Beschaffenheitsgarantie"). The specifications of SEMIKRON products describe only the usual characteristics of products to be expected in typical applications, which may still vary depending on the specific application. Therefore, products must be tested for the respective application in advance. Application adjustments may be necessary. The user of SEMIKRON products is responsible for the safety of their applications embedding SEMIKRON products and must take adequate safety measures to prevent the applications from causing a physical injury, fire or other problem if any of SEMIKRON products become faulty. The user is responsible to make sure that the application design is compliant with all applicable laws, regulations, norms and standards. Except as otherwise explicitly approved by SEMIKRON in a written document signed by authorized representatives of SEMIKRON, SEMIKRON products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury. No representation or warranty is given and no liability is assumed with respect to the accuracy, completeness and/or use of any information herein, including without limitation, warranties of non-infringement of intellectual property rights of any third party. SEMIKRON does not assume any liability arising out of the applications or use of any product; neither does it convey any license under its patent rights, copyrights, trade secrets or other intellectual property rights, nor the rights of others. SEMIKRON makes no representation or warranty of non-infringement or alleged non-infringement of intellectual property rights of any third party which may arise from applications. Due to technical requirements our products may contain dangerous substances. For information on the types in question please contact the nearest SEMIKRON sales office. This document supersedes and replaces all information previously supplied and may be superseded by updates. SEMIKRON reserves the right to make changes.

6 Rev. 3.0 – 06.08.2021 © by SEMIKRON